



**Features** 

DMT6009LK3

#### **60V N-CHANNEL ENHANCEMENT MODE MOSFET**

Small Form Factor Thermally Efficient Package Enables Higher

Low R<sub>DS(ON)</sub> – Ensures On State Losses Are Minimized

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Case Material: Molded Plastic, "Green" Molding Compound.

Terminal Finish - Matte Tin Annealed over Copper Leadframe;

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 @3

Weight: 0.33 grams (Approximate)

Excellent Q<sub>gd x</sub> R<sub>DS(ON)</sub> Product (FOM) Advanced Technology for DC/DC Converters

**Density End Products** 

Case: TO252

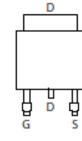
## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	10mΩ @ V <sub>GS</sub> = 10V	57A
60V	12.8m $\Omega$ @ V <sub>GS</sub> = 4.5V	51A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high- efficiency power management applications.

- Power Management Functions
- DC-DC Converters
- Backlighting



Pin Out Top View

s

Equivalent Circuit

Ordering Information (Note 4)

Top View

Part Number	Case	Packaging
DMT6009LK3-13	TO252	2,500/Tape & Reel

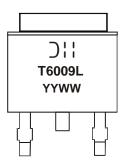
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



) | | =Manufacturer's Marking T6009L = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 15 = 2015) WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	60	V
Gate-Source Voltage		V <sub>GSS</sub>	±16	V
Continuous Drain Current (Note 5) $V_{GS} = 10V$	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	13.3 10.6	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$		ID	57 46	А
Maximum Continuous Body Diode Forward Current (Note	e 6)	ls	80	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	90	А
Avalanche Current, L=0.1mH		I <sub>AS</sub>	20.3	А
Avalanche Energy, L=0.1mH		E <sub>AS</sub>	20.6	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	47	°C/W
Total Power Dissipation (Note 6)	PD	50	W
Thermal Resistance, Junction to Case (Note 6)	R <sub>θJC</sub>	2.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	-	-	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.7	1.4	2	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		-	8.3	10	mΩ	$V_{GS} = 10V, I_D = 13.5A$	
	R <sub>DS(ON)</sub>	-	9.6	12.8	mΩ	$V_{GS} = 4.5V, I_D = 11.5A$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	-	1,925	-		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	-	438	-	pF		
Reverse Transfer Capacitance	Crss	-	41	-			
Gate Resistance	R <sub>g</sub>	-	1.7	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	-	15.6	-	-		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	-	33.5	-			
Gate-Source Charge	Q <sub>qs</sub>	-	4.7	-	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 13.5A	
Gate-Drain Charge	Q <sub>gd</sub>	-	5.3	-			
Turn-On Delay Time	t <sub>D(ON)</sub>	-	4.5	-			
Turn-On Rise Time	t <sub>R</sub>	-	8.6	-		$\label{eq:VDD} \begin{split} V_{DD} &= 30 V, \ V_{GS} = 10 V, \\ R_G &= 6 \Omega, \ I_D = 13.5 A \end{split}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	35.9	-	ns		
Turn-Off Fall Time	tF	-	15.7	-			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	18.2	-	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	-	33.1	-	nC	I <sub>F</sub> = 13.5A, di/dt = 400A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

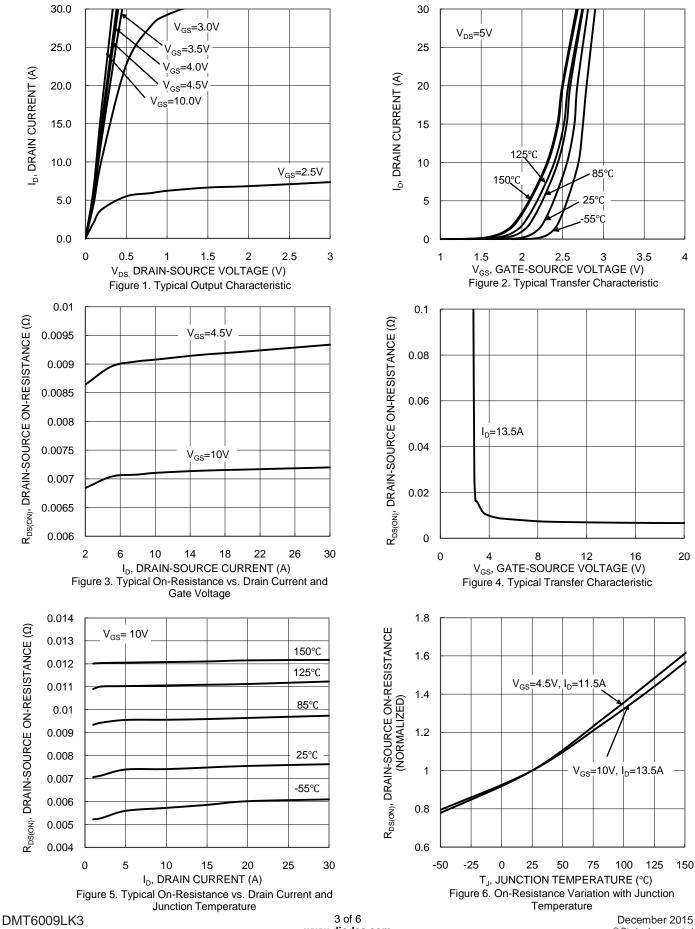
6. Device mounted on infinite heat sink and measured by thermal couple attached on bottom heat sink of package.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



### DMT6009LK3



Document number: DS38207 Rev. 3 - 2

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## DMT6009LK3

I<sub>D</sub>=1mA

100 125

C<sub>iss</sub>

Coss

C<sub>rss</sub>

20

25

P

P<sub>W</sub>=10s

10

=100µs

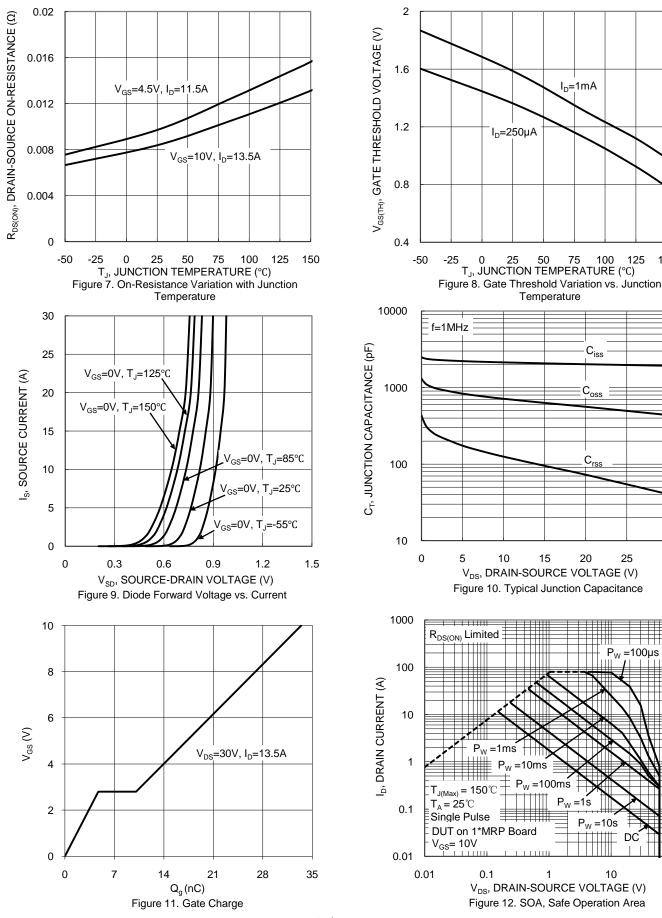
30

15

=100ms

1

150



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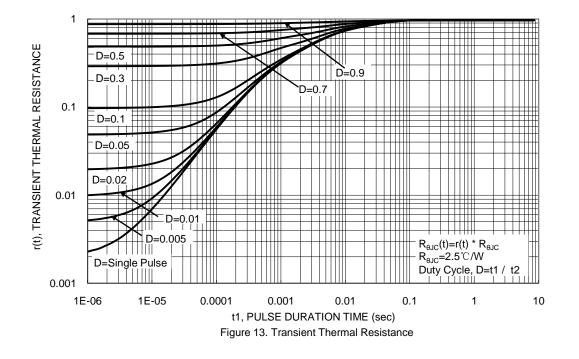
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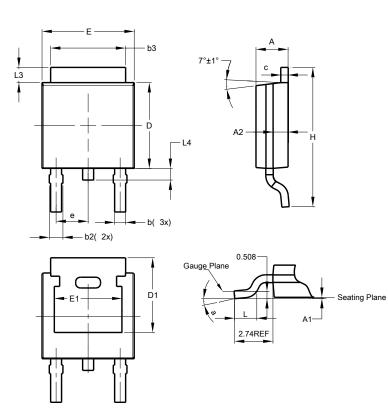
DC





# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

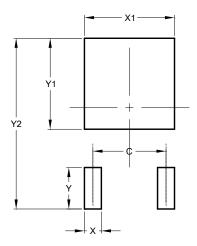


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All	All Dimensions in mm				



### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		

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